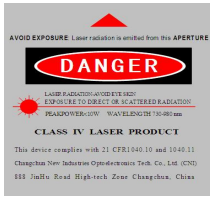
MLL-III-785-Lock/1-600mW

LOW NOISE INFRARED DIODE LASER AT 785nm

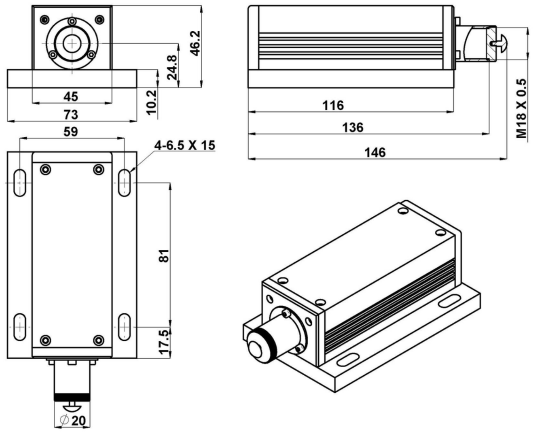
It features ultra compact design, long lifetime, cost-effectiveness and easy operation. They are specially designed for Raman spectroscopy, measurement, communication, spectrum analysis, etc.

SPECIFICATIONS

Central wavelength (nm)	785±0.6
Spectral line width (nm)	<0.2, <0.1, <0. 06
Operating mode	CW
Output power (mW)[1]	1-600
Power stability (rms, 4 hours ± 3°C)	<2%, <1%, <0.5%
Transverse mode	Multimode
Noise of amplitude (rms, 20Hz-20MHz)	<1%, <0.5%
Beam diameter at the aperture (mm)	~10×1
Beam divergence, full angle (mrad)	<3.0
Warm-up time (minutes)	<5
Cooled method	Conduction
Beam height from base plate (mm)	24.8
Operating temperature (°C)	10-35
Power supply (100-240VAC)	PSU-III-FDA/PSU-III-LED/PSU-A-D/PSU-III-OEM
Modulation option	DC-1kHz, 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional; TTL and Analog optional
Expected lifetime (hours)	>10000

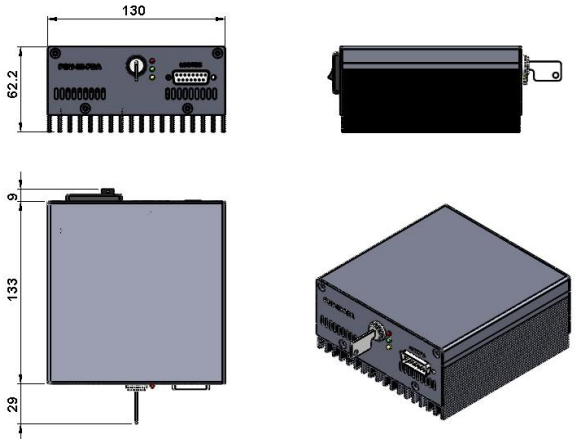


LASER HEAD



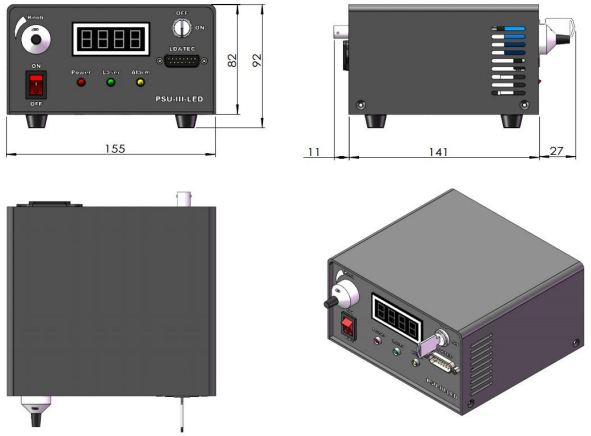
146 (L) ×73 (W) ×46. 2 (H) mm³, 0.7kg

POWER SUPPLY (PSU-III-FDA)[2]



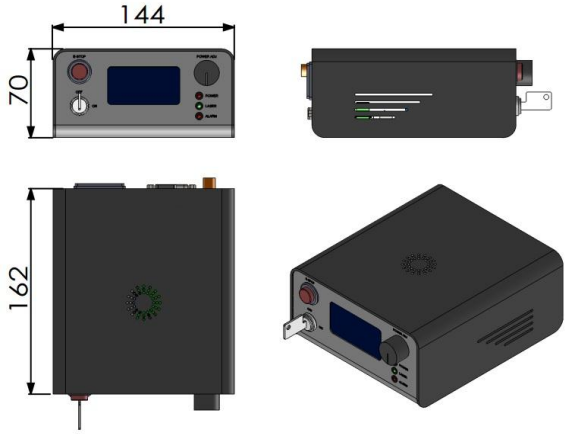
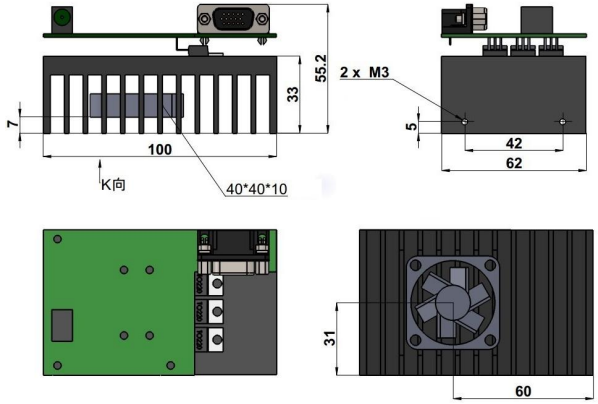
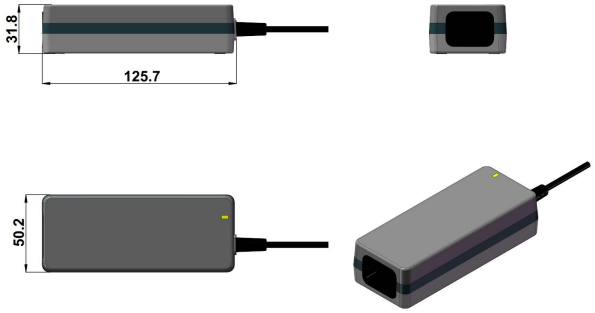
171 (L) ×130 (W) ×62.2 (H) mm³, 1.2kg

POWER SUPPLY (PSU-III-LED)[3]



179 (L) ×155 (W) ×92 (H) mm³, 1.5kg

Website: http://www.cnilaser.com E-mail: sales@cnilaser.com Tel: +86-431-85603799 Fax: +86-431-89216068

POWER SUPPLY (PSU-A-D)[4]	DRIVER (PSU-III-OEM)[2]	POWER SUPPLY (100-240VAC) optional
		
162 (L) ×144 (W) ×70 (H) mm³, 1.0kg	**100 (L) ×62 (W) ×55.2 (H) mm³, 0.5kg**	**125.7 (L) ×50.2 (W) ×31.8 (H) mm³, 0.3kg**

1 Any power level can be selected in this range.

2 Fixed output power; Modulation up to 30kHz.

3 Output power adjustable 10-100%; RS232 control optional; Modulation up to 30kHz.

4 Output power adjustable 10-100%; RS232 control optional; Modulation up to 100kHz.